

ble above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit	
V <sub>CEO</sub>	Collector-Emitter Voltage	160	V	
V <sub>CBO</sub>	Collector-Base Voltage	180	V	
V <sub>EBO</sub>	Emitter-Base Voltage	6	V	
۱ <sub>C</sub>	Collector Current (DC)	600	mA	
ТJ	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C	

## Thermal Characteristics<sup>(1), (2)</sup>

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Value	Unit
P <sub>D</sub>	Power Dissipation ( $T_C = 25^{\circ}C$ )	0.7	W
	Derate Above 25°C	5.6	mW/°C
R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient	180	°C/W

Notes:

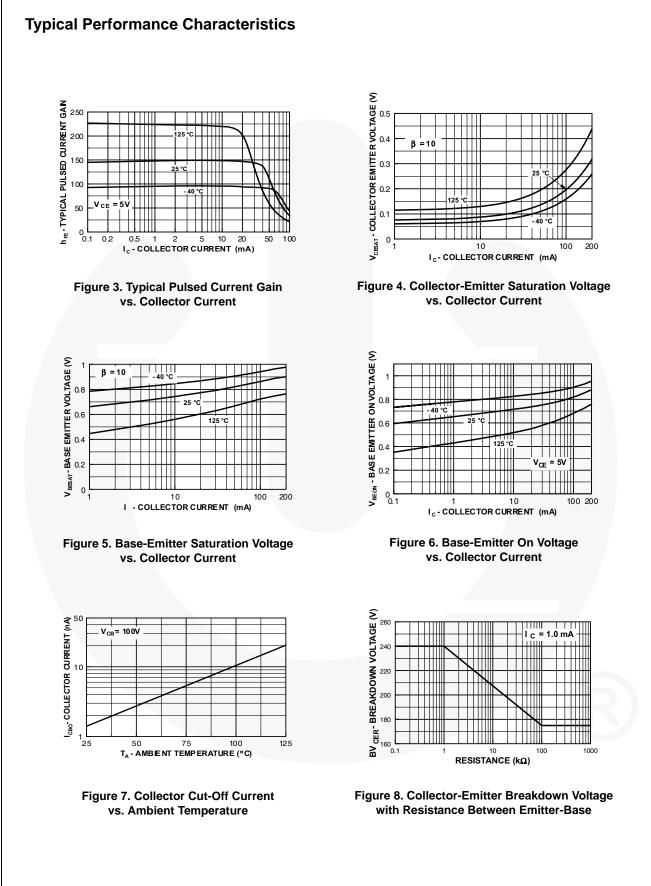
1.  $P_D$  total, for both transistors. For each transistor,  $P_D$  = 350 mW.

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

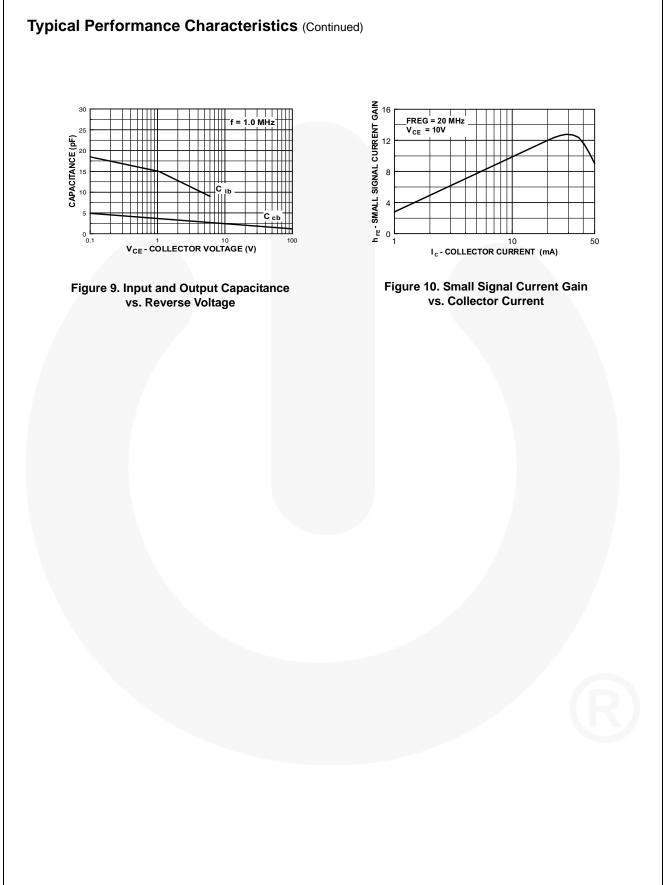
## **Electrical Characteristics**

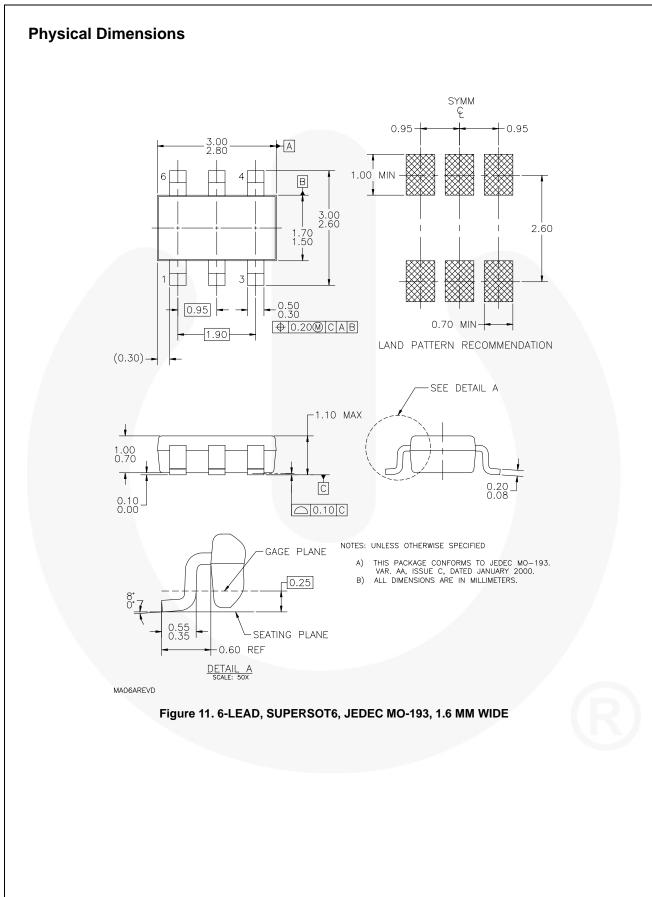
Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit	
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 1  {\rm mA},  I_{\rm B} = 0$	160		V	
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu \text{A}, \ I_{\rm E} = 0$	180		V	
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	6		V	
I <sub>CBO</sub>	Collector Cut-Off Current	$V_{CB} = 120 \text{ V}, \text{ I}_{E} = 0$		50	nA	
		$V_{CB} = 120 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 100^{\circ}\text{C}$		50	μA	
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = 4 V, I_{C} = 0$		50	nA	
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = 5 V, I_{C} = 1 mA$	80			
DIVID1	Variation Ratio of h <sub>FE1</sub> Between Die 1 and Die 2	h <sub>FE1</sub> (Die1) / h <sub>FE1</sub> (Die2)	0.9	1.1		
h <sub>FE2</sub>	DC Current Gain	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	80	250		
DIVID2	Variation Ratio of h <sub>FE2</sub> Between Die 1 and Die 2	h <sub>FE2</sub> (Die1) / h <sub>FE2</sub> (Die2)	0.95	1.05		
h <sub>FE3</sub>	DC Current Gain	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 50 \text{ mA}$	30			
DIVID3	Variation Ratio of h <sub>FE3</sub> Between Die 1 and Die 2	h <sub>FE3</sub> (Die1) / h <sub>FE3</sub> (Die2)	0.9	1.1		
V <sub>CE</sub> (sat)		I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA		0.15	- v	
	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5 \text{ mA}$		0.20		
N/ (1)	Base-Emitter Saturation Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1 \text{ mA}$		1	V	
V <sub>BE</sub> (sat)	Base-Emilier Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5 \text{ mA}$		1	v	
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$		1	V	
DEL	Difference of V <sub>BE</sub> (on) Between Die1 and Die 2	V <sub>BE</sub> (on)(Die1) - V <sub>BE</sub> (on)(Die2)	-8	8	mV	
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		6	pF	
C <sub>ib</sub>	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1 \text{ MHz}$		20	pF	
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA},$ f = 100 MHz	100	300	MHz	
NF	Noise Figure	$V_{CE} = 5 \text{ V}, I_C = 200 \mu\text{A},$ f = 1 MHz, R <sub>S</sub> = 20 k $\Omega$ , B = 200 Hz		8	dB	
h <sub>fe</sub>	Small Signal Current Gain	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 1.0 \text{ mA},$ f = 10 kHz	50	250		



FMBM5551 — NPN General-Purpose Amplifier





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